TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

# 2SC5096FT

#### VHF~UHF Band Low Noise Amplifier Applications

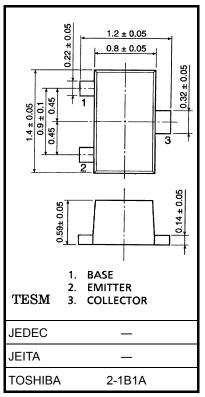
- Low noise figure, high gain.
- NF = 1.8dB,  $|S_{21e}|^2 = 7.5dB$  (f = 2 GHz)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	20	V
Collector-emitter voltage	V <sub>CEO</sub>	8	V
Emitter-base voltage	V <sub>EBO</sub>	1.5	V
Base current	Ι <sub>Β</sub>	7	mA
Collector current	ΙC	15	mA
Collector power dissipation	P <sub>C</sub>	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.0022 g (typ.)

#### **Microwave Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f <sub>T</sub>	$V_{CE} = 6 V, I_C = 7 mA$	7	10	_	GHz
Insertion gain	S <sub>21e</sub>   <sup>2</sup> (1)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 7 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	13	—	dB
	S <sub>21e</sub>   <sup>2</sup> (2)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 7 \text{ mA}, \text{ f} = 2 \text{ GHz}$	4.5	7.5	—	
Noise figure	NF (1)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 3 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	1.4	—	dB
	NF (2)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 3 \text{ mA}, \text{ f} = 2 \text{ GHz}$		1.8	3.0	uВ

#### **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0$	_	_	1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 1 \text{ V}, \text{ I}_{C} = 0$			1	μA
DC current gain	h <sub>FE</sub> (Note 1)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 7 \text{ mA}$	50		160	
Output capacitance	Cob	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$ (Note 2)		0.5	_	pF
Reverse transfer capacitance	C <sub>re</sub>		_	0.4	0.85	pF

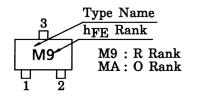
Note 1: hFE classification R: 50~100, O: 80~160

Note 2: Cre is measured by 3 terminal method with capacitance bridge.

Unit: mm

## **TOSHIBA**

### Marking



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20070701-EN GENERAL

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